Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Glass
Overall Length:
0.250 inches
Terminal Length:
0.700 inches
Overall Diameter:
0.085 inches
End Application:
Satellite communications set, an/wsc- (v) 9
Mounting Method:
Terminal
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
60.0 regulator voltage
Current Rating Per Characteristic:
50.00 milliamperes dc current in reverse breakdown region and 600.00 milliamperes source current
Power Rating Per Characteristic:
3.0 watts total device dissipation
Maximum Operating Tempurature Per Measurement Point:
125.0 degrees celsius ambient air
Terminal Type And Quantity:
2 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
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